

TOSHIBA Photocoupler GaAlAs IRED + Photo IC

TLP701

Industrial inverters

Inverter for air conditioners

IGBT/Power MOS FET gate drive

TLP701 consists of a GaAlAs light-emitting diode and an integrated photodetector.

This unit is 6-lead SDIP package. The TLP701 is 50% smaller than the 8-pin DIP and meets the reinforced insulation class requirements of international safety standards. Therefore the mounting area can be reduced in equipment requiring safety standard certification.

The TLP701 is suitable for gate driving circuits for IGBTs or power MOSFETs. In particular, the TLP701 is capable of "direct" gate driving of low-power IGBTs.

- Peak output current : ± 0.6 A (max)
 - Guaranteed performance over temperature : -40 to 100°C
 - Supply current : 2 mA (max)
 - Power supply voltage : 10 to 30 V
 - Threshold input current : $I_{FLH} = 5$ mA (max)
 - Switching time (t_{PLH} / t_{PHL}) : 700 ns (max)
 - Common mode transient immunity : ± 10 kV/ μ s (min)
 - Isolation voltage : 5000 Vrms (min)
 - Construction mechanical rating

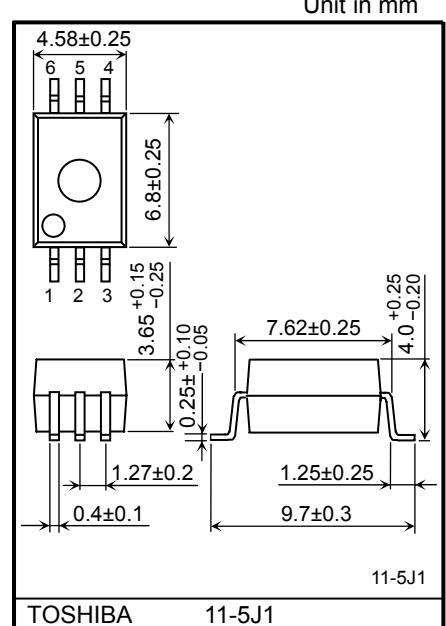
| | 7.62-mm pitch standard type | 10.16-mm pitch TLPXXXF type |
|----------------------|--------------------------------|--------------------------------|
| Creepage Distance | 7.0 mm (min) | 8.0 mm (min) |
| Clearance | 7.0 mm (min) | 8.0 mm (min) |
| Insulation Thickness | 0.4 mm (min) | 0.4 mm (min) |

- UL Recognized : UL1577, File No. E67349
 - Option (D4)
TÜV approved : EN60747-5-2
Certificate No. R50033433
 - Maximum operating insulation voltage : 890 Vpk
 - Highest permissible over voltage : 8000 Vpk

(Note) When a EN60747-5-2 approved type is needed,
please designate the “Option(D4)”

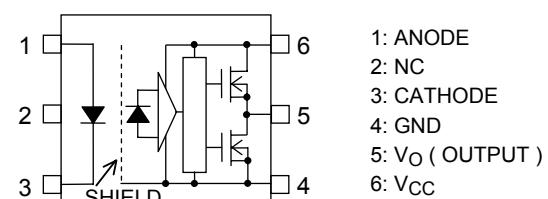
Truth Table

| Input | LED | Tr1 | Tr2 | Output |
|-------|-----|-----|-----|--------|
| H | ON | ON | OFF | H |
| L | OFF | OFF | ON | L |

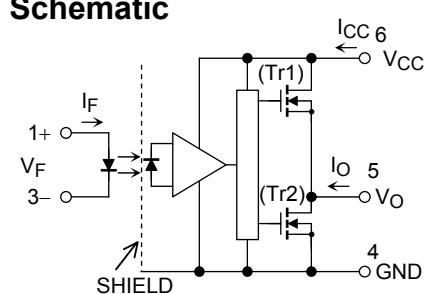


Weight : 0.26 g (typ.)

Pin Configuration (Top View)



Schematic



A 0.1- μ F bypass capacitor must be connected between pins 6 and 4. (See Note 6.)

Maximum Ratings (Ta = 25 °C)

| Characteristics | | Symbol | Rating | Unit |
|---|---|----------------------|------------|-------|
| LED | Forward current | I _F | 20 | mA |
| | Forward current derating (Ta ≥ 85°C) | ΔI _F /ΔTa | -0.54 | mA/°C |
| | Peak transient forward current (Note 1) | I _{FP} | 1 | A |
| | Reverse voltage | V _R | 5 | V |
| | Junction temperature | T _j | 125 | °C |
| Detector | "H" peak output current (Note 2) | I _{OPH} | -0.6 | A |
| | "L" peak output current (Note 2) | I _{OPL} | 0.6 | A |
| | Output voltage | V _O | 35 | V |
| | Supply voltage | V _{CC} | 35 | V |
| | Junction temperature | T _j | 125 | °C |
| Operating frequency (Note 3) | | f | 25 | kHz |
| Operating temperature range | | T _{opr} | -40 to 100 | °C |
| Storage temperature range | | T _{stg} | -55 to 125 | °C |
| Lead soldering temperature (10 s) (Note 4) | | T _{sol} | 260 | °C |
| Isolation voltage (AC, 1 minute, R.H. ≤ 60%) (Note 5) | | BV _S | 5000 | Vrms |

Note 1: Pulse width P_W ≤ 1 μs, 300 pps

Note 2: Exponential waveform pulse width P_W ≤ 2 μs, f ≤ 15 kHz

Note 3: Exponential waveform I_{OPH} ≤ -0.3 A (≤ 2 μs), I_{OPL} ≤ +0.3 A (≤ 2 μs), Ta = 100 °C

Note 4: For the effective lead soldering area

Note 5: Device considered a two-terminal device: pins 1, 2 and 3 paired with pins 4, 5 and 6 respectively.

Note 6: A ceramic capacitor (0.1 μF) should be connected from pin 6 to pin 4 to stabilize the operation of the high gain linear amplifier. Failure to provide the bypassing may impair the switching property.

The total lead length between capacitor and coupler should not exceed 1 cm.

Recommended Operating Conditions

| Characteristics | Symbol | Min | Typ. | Max | Unit |
|----------------------------|-------------------------------------|-----|------|-------|------|
| Input current, ON (Note 7) | I _F (ON) | 7.5 | — | 10 | mA |
| Input voltage, OFF | V _F (OFF) | 0 | — | 0.8 | V |
| Supply voltage | V _{CC} | 10 | — | 30 | V |
| Peak output current | I _{OPH} / I _{OPL} | — | — | ± 0.2 | A |
| Operating temperature | T _{opr} | -40 | — | 100 | °C |

Note 7: Input signal rise time (fall time) < 0.5 μs.

Electrical Characteristics (Ta = -40 to 100 °C, unless otherwise specified)

| Characteristics | | Symbol | Test Circuit | Test Condition | | Min | Typ.* | Max | Unit |
|--|-----------|----------------------|--------------|--|--|------|-------|------|-------|
| Forward voltage | | V _F | — | I _F = 5 mA, Ta = 25 °C | | — | 1.55 | 1.70 | V |
| Temperature coefficient of forward voltage | | ΔV _F /ΔTa | — | I _F = 5 mA | | — | -2.0 | — | mV/°C |
| Input reverse current | | I _R | — | V _R = 5 V, Ta = 25 °C | | — | — | 10 | μA |
| Input capacitance | | C _T | — | V = 0 V, f = 1 MHz, Ta = 25 °C | | — | 45 | — | pF |
| Output current (Note 8) | "H" Level | I _{OPH1} | 1 | V _{CC} = 15 V I _F = 5 mA | V ₆₋₅ = 4 V | -0.2 | -0.38 | — | A |
| | | I _{OPH2} | | | V ₆₋₅ = 10 V | -0.4 | -0.60 | — | |
| | "L" Level | I _{OPL1} | 2 | V _{CC} = 15 V I _F = 0 mA | V ₅₋₄ = 2 V | 0.2 | 0.36 | — | |
| | | I _{OPL2} | | | V ₅₋₄ = 10 V | 0.4 | 0.62 | — | |
| Output voltage | "H" Level | V _{OH} | 3 | V _{CC} = 10 V | I _O = -100 mA, I _F = 5 mA | 6.0 | 8.5 | — | V |
| | "L" Level | V _{OL} | 4 | | I _O = 100 mA, V _F = 0.8 V | — | 0.4 | 1.0 | |
| Supply current | "H" Level | I _{CCH} | 5 | V _{CC} = 10 to 30 V V _O =Open | I _F = 10 mA | — | 1.4 | 2.0 | mA |
| | "L" Level | I _{CCL} | 6 | | I _F = 0 mA | — | 1.3 | 2.0 | |
| Threshold input current | L → H | I _{FLH} | — | V _{CC} = 15 V, V _O > 1 V | | — | 2.5 | 5 | mA |
| Threshold input voltage | H → L | V _{FHL} | — | V _{CC} = 15 V, V _O < 1 V | | 0.8 | — | — | V |
| Supply voltage | | V _{CC} | — | — | | 10 | — | 30 | V |

(*): All typical values are at Ta = 25°C

Note 8: Duration of I_O time ≤ 50 μs, 1 pulse

Note 9: This product is more sensitive than conventional products to electrostatic discharge (ESD) owing to its low power consumption design.

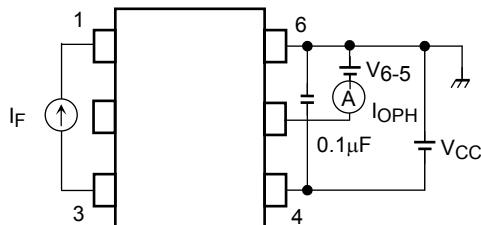
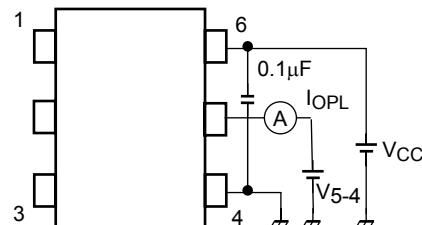
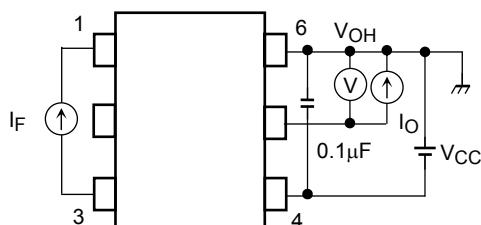
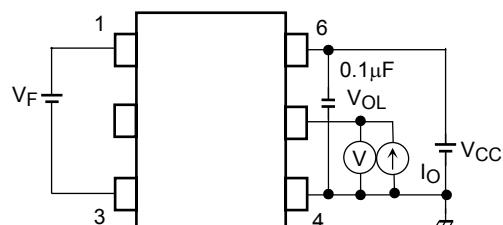
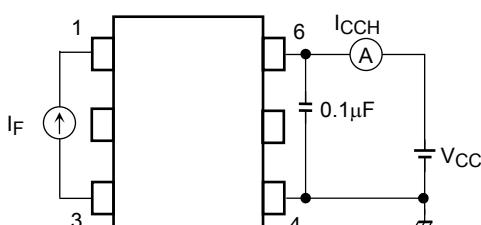
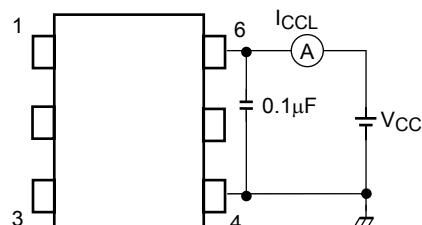
It is therefore all the more necessary to observe general precautions regarding ESD when handling this component.

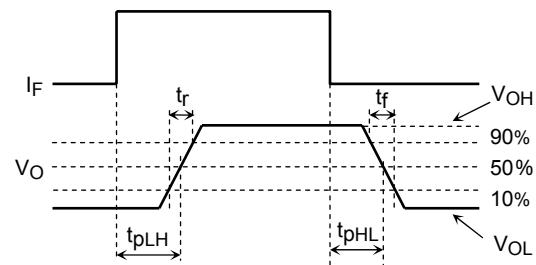
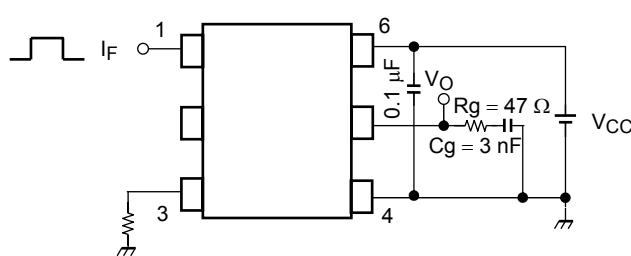
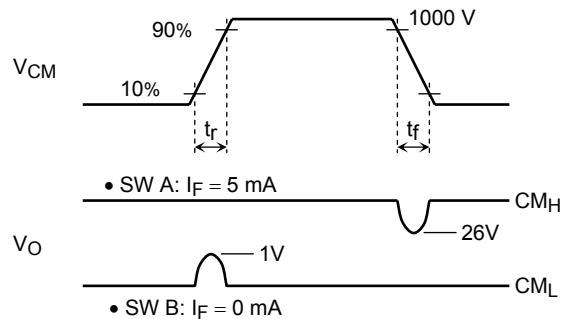
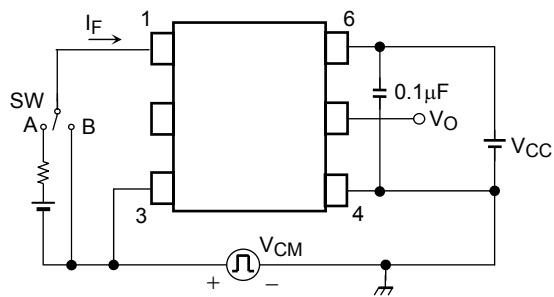
Isolation Characteristics (Ta = 25 °C)

| Characteristic | Symbol | Test Condition | | Min. | Typ. | Max. | Unit |
|-----------------------------|----------------|--|--|--------------------|------------------|------|------|
| Capacitance input to output | C _S | V = 0 V, f = 1MHz (Note 5) | | — | 1.0 | — | pF |
| Isolation resistance | R _S | R.H. ≤ 60 %, V _S = 500 V (Note 5) | | 1×10 ¹² | 10 ¹⁴ | — | Ω |
| Isolation voltage | BVs | AC, 1 minute | | 5000 | — | — | Vrms |
| | | AC, 1 second, in oil | | — | 10000 | — | |
| | | DC, 1 minute, in oil | | — | 10000 | — | Vdc |

Switching Characteristics ($T_a = -40$ to 100 °C, unless otherwise specified)

| Characteristics | | Symbol | Test Circuit | Test Condition | | Min | Typ.* | Max | Unit |
|---|--|---------------------|--|---|--|--------|-------|-----|------------------------|
| Propagation delay time | | t_{PLH} | 7 V _{CC} = 30 V $R_g = 47 \Omega$ $C_g = 3 \text{ nF}$ | $I_F = 0 \rightarrow 5 \text{ mA}$ | | 100 | — | 700 | ns |
| | | t_{PHL} | | $I_F = 5 \rightarrow 0 \text{ mA}$ | | 100 | — | 700 | |
| Output rise time (10–90 %) | | t_r | | $I_F = 0 \rightarrow 5 \text{ mA}$ | | — | 50 | — | |
| | | t_f | | $I_F = 5 \rightarrow 0 \text{ mA}$ | | — | 50 | — | |
| Switching time dispersion between ON and OFF | | $ t_{PHL}-t_{PLH} $ | | $I_F = 0, 5 \text{ mA}$ | | -500 | — | 500 | |
| Common mode transient immunity at HIGH level output | | CM_H | 8 $V_{CM} = 1000 \text{ Vp-p}$ $V_{CC} = 30 \text{ V}$ $T_a = 25^\circ\text{C}$ | $I_F = 5 \text{ mA}$ $V_O (\text{min}) = 26 \text{ V}$ | | -10000 | — | — | $\text{V}/\mu\text{s}$ |
| Common mode transient immunity at LOW level output | | CM_L | | $I_F = 0 \text{ mA}$ $V_O (\text{max}) = 1 \text{ V}$ | | 10000 | — | — | |

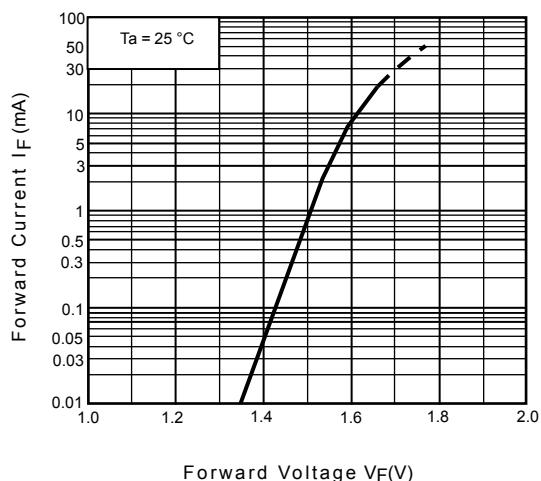
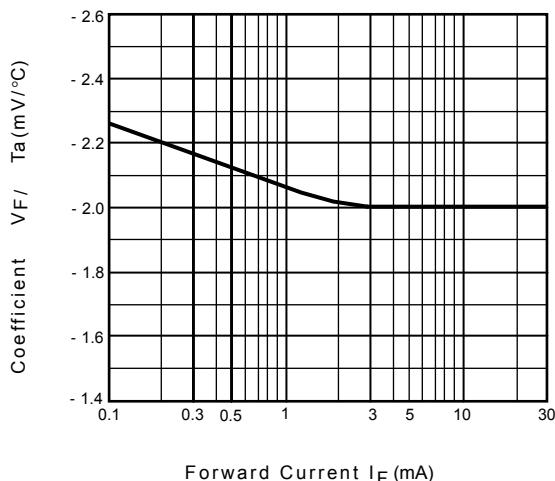
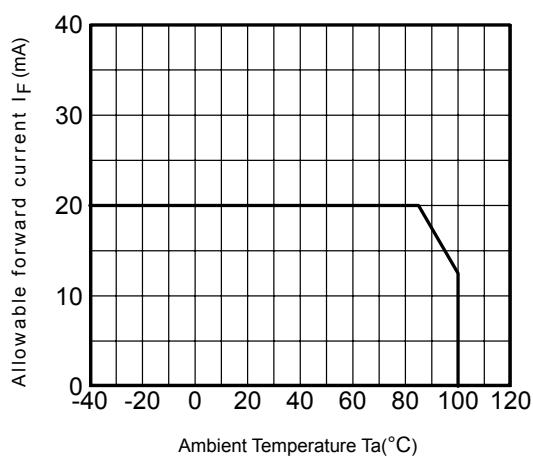
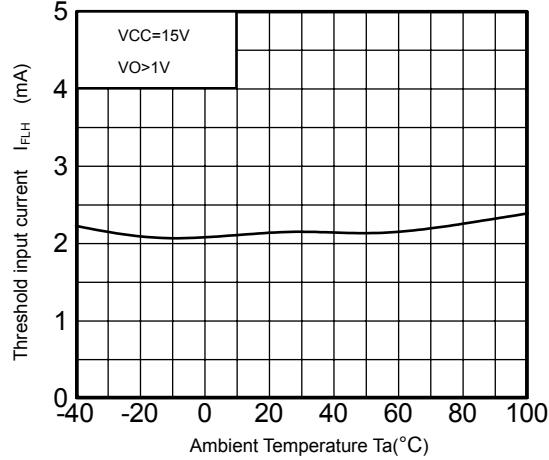
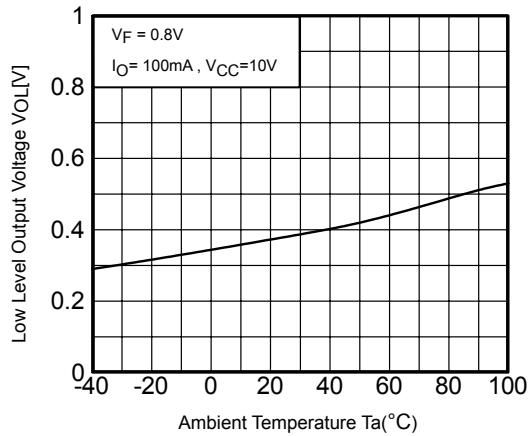
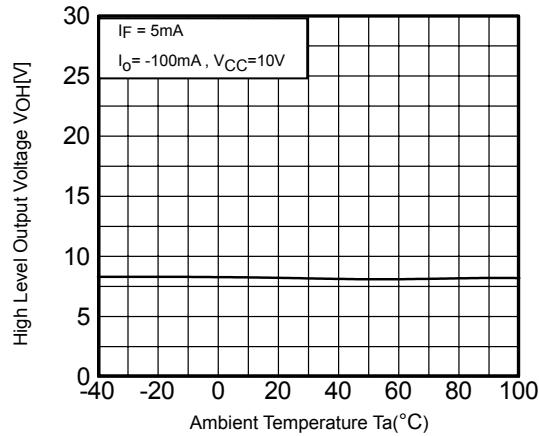
(*): All typical values are at $T_a = 25^\circ\text{C}$.Test Circuit 1: I_{OPH} Test Circuit 2: I_{OPL} Test Circuit 3: V_{OH} Test Circuit 4: V_{OL} Test Circuit 5: I_{CCH} Test Circuit 6: I_{CCL} 

Test Circuit 7: t_{PLH} , t_{PHL} , t_r , t_f , PDD**Test Circuit 8: CM_H , CM_L** 

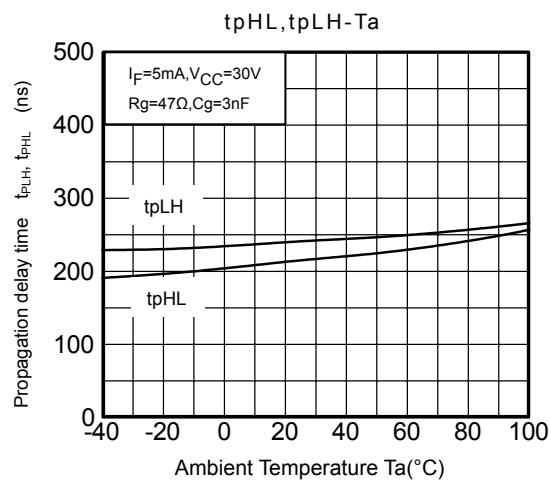
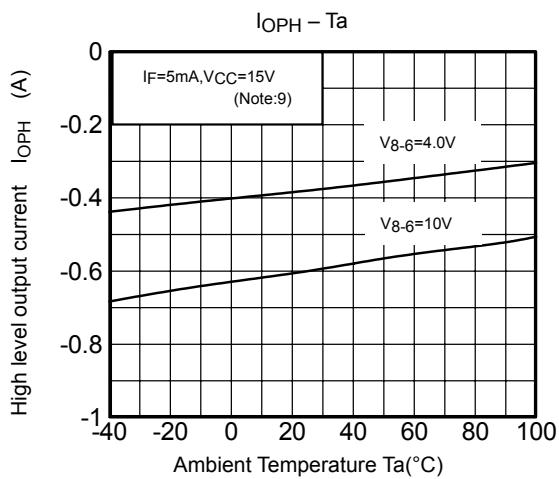
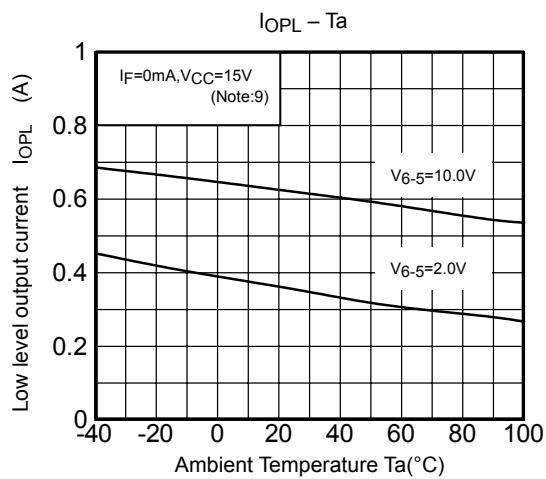
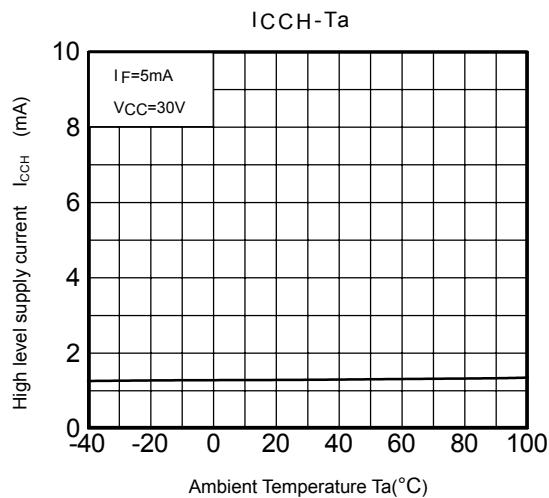
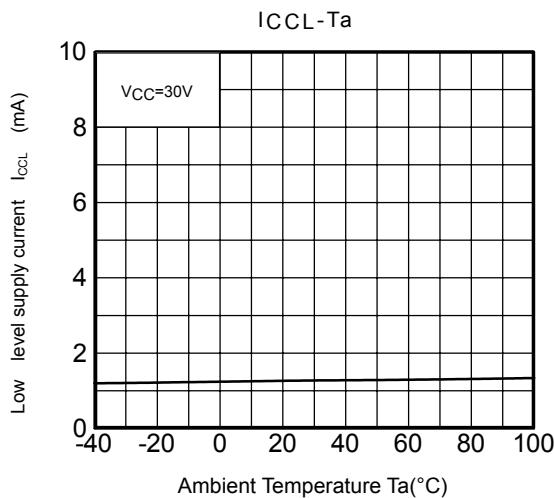
$$CM_L = \frac{800 \text{ V}}{t_r (\mu\text{s})}$$

$$CM_H = - \frac{800 \text{ V}}{t_f (\mu\text{s})}$$

CM_L (CM_H) is the maximum rate of rise (fall) of the common mode voltage that can be sustained with the output voltage in the LOW (HIGH) state.

$I_F - V_F$  $V_F / Ta - I_F$  $I_F - Ta$  $I_{FLH} - Ta$  $V_{OL} - Ta$  $V_{OH} - Ta$ 

*: The above graphs show typical characteristics.



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